NSN 5961-01-252-8712 Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-252-8712
Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.370 inches
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-39
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.210 inches
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Zzzy
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-100.0 drain to gate voltage and -100.0 drain to source voltage and 20.0 gate to source voltage
Current Rating Per Characteristic:
-5.00 amperes off-state current, peak
Power Rating Per Characteristic:
1.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Item must comply with requirements of defense supply center columbus production standard no. Lo3705
Terminal Type And Quantity:
3 uninsulated wire lead
Reference Number Differentiating Characteristics:
Reference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing
and testing specifications available at the dla icp
Shelf Life:
N/a
Unit Of Measure:

NSN 5961-01-252-8712

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0